999 – Probing the Cation Distribution in Gamma-Alumina Enabled by O-K Edge Artifact Suppression Using Cryo-EELS

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Gamma-alumina (γ-Al_2O_3) is one of several transitional phases of Al_2O_3 with valuable properties that render it highly useful in a number of applications including catalysis and absorbents. Yet despite the technological importance of γ-Al_2O_3, its crystal structure is still not fully understood. While γ-Al_2O_3 was originally described as having a spinel-like structure [1], many different spinel-based and nonspinel structures have since been proposed. In our previous work, we verified that the cubic spinel-based model is indeed the most accurate for γ-Al_2O_3 [2]. However, the distribution of Al cations in the lattice remains unclear. Since cation vacancies must be added to the normal spinel structure to achieve the correct stoichiometry of Al_2O_3, the placement of the vacancies in either tetrahedral or octahedral sites determines the Al cation distribution. Prior studies have reached contradictory conclusions, with some claiming all vacancies are on octahedral sites [3], some suggesting all vacancies are on tetrahedral sites [4], and some claiming a mixed distribution [5]. Determining the cation distribution is key to accurately modeling γ-Al_2O_3 for various theoretical simulations, including catalytic property simulations which are of great interest to the chemical engineering community.

Electron energy-loss spectroscopy (EELS) is a distinctly suitable tool for this study due to the sensitivity of the energy-loss near-edge fine structure (ELNES) to local atomic coordination. We therefore employed scanning transmission electron microscopy (STEM) and monochromated EELS combined with multiple scattering ELNES simulations to investigate the Al atom distribution in the spinel γ-Al_2O_3 structure. A major factor contributing to the uncertainty around the structure of γ-Al_2O_3 is the heterogeneity of commercially available γ-Al_2O_3. To address this, we synthesized single-crystalline γ-Al_2O_3 thin films through thermal oxidation of single-crystal NiAl (110). From the highly crystalline ~80 nm γ-Al_2O_3 thin films, cross-sectional TEM samples were prepared using focused ion beam (FIB) for the STEM-EELS experiments.

One of the requirements to collect accurate, high-quality STEM-EELS data is the use of sufficiently high electron beam currents. However, like many other low-Z oxide materials, γ-Al_2O_3 is highly susceptible to structural changes by the highly focused STEM electron beam. Knock-on damage as well as radiolysis effects could occur, easily observed as holes in the sample (Figure 1a) or as changes in the

pre-edge fine structure in the O-K EELS edge (Figure 1b). Therefore, we first employed a carefully systematic study investigating the origin of beam effects on γ-Al_2O_3, in order to find optimum experimental conditions minimizing these beam effects. We found that employing cryogenic conditions – using a liquid nitrogen-cooled Gatan cryo-holder – was most effective in mitigating the impact of beam effects on EELS spectra; more so than reducing acceleration voltage (HT). Even under high HT conditions where knock-on damage (hole) was still present, the pre-edge peak in the O-K EELS spectrum could be completely suppressed under cryo conditions (Figure 1c,d). ELNES simulations were used to explain the source of the damage-related pre-edge peak as likely due to surface O-O bonds formed as a result of the beam-sample interaction.

Using our optimized EELS experimental conditions, Al-K, Al-$L_{2,3}$, and O-K edge ELNES were acquired at cryogenic temperatures from the cross-sectional γ-Al_2O_3 sample to investigate the cation distribution of γ-Al_2O_3. Al-$L_{2,3}$ and O-K edge ELNES were simulated for the differently coordinated Al and O atoms in the spinel γ-Al_2O_3 structure using the FEFF9 code [6]. Simulated Al-$L_{2,3}$ ELNES of tetrahedral and octahedral Al atoms shows a clear dependence of the spectrum shape on the Al coordination (Figure 2a). Comparing the simulated O-K edge ELNES for the different nonequivalent O sites reveals that shoulder on the first peak varies in intensity as a function of the nearest-neighbor coordination around the scattering O atom, providing a gauge of the relative fractions of the different O atom environments in γ-Al_2O_3 (Figure 2). This is an indirect measure of the Al atom distribution since the O atom environment is dependent on the Al atom distribution in the lattice. Further simulations of the Al-$L_{2,3}$ and Al-K edges will be presented to directly probe the Al cation distribution and to determine tetrahedral and octahedral Al contributions in our experimental EELS data.
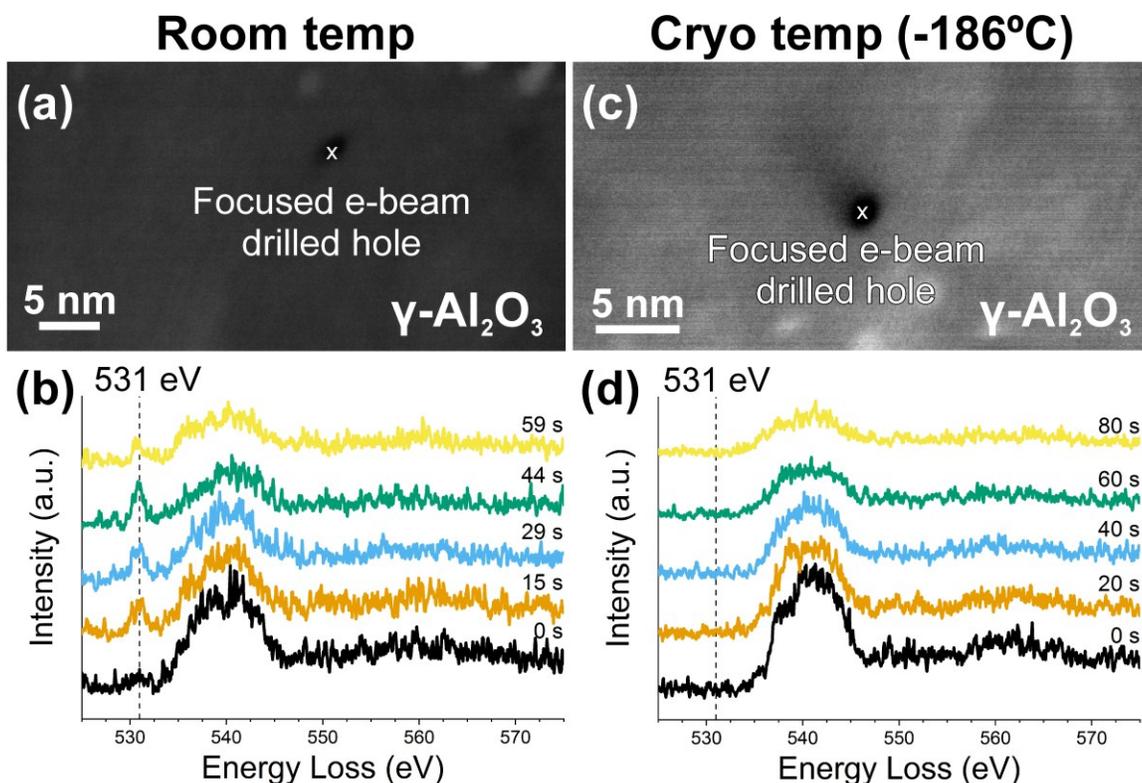
Figure 1. Figure 1. (a) Dark-field STEM image of γ-Al_2O_3 with the position where the focused electron beam was used to drill a hole marked with an x. (b) Time-resolved O-K edge EELS spectra acquired at room temperature during e-beam hole drilling. The characteristic damage-associated pre-edge peak at 531 eV is marked with the dotted line. (c) DF-STEM image of γ-Al_2O_3 in the cryo experiments. (d) Time-resolved O-K edge EELS spectra acquired at cryogenic temperature during e-beam hole drilling with no pre-edge peak observable.
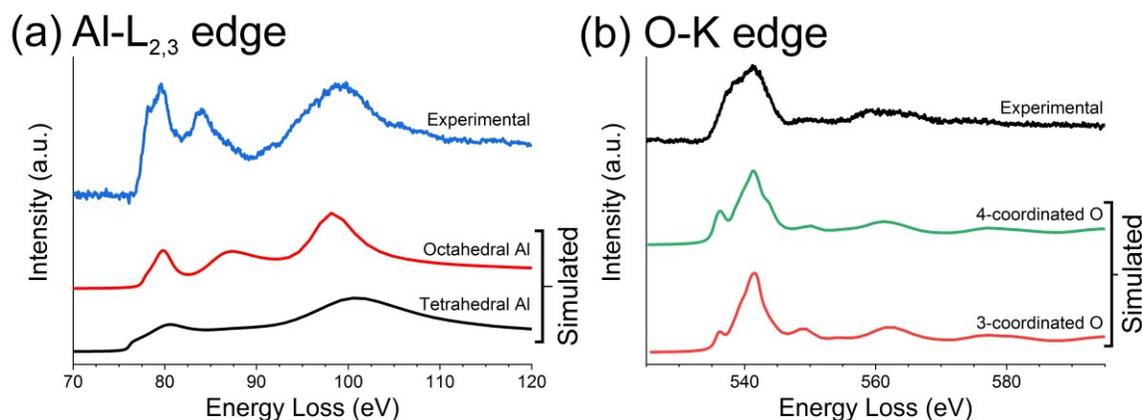
Figure 2. Figure 2. Comparison of experimental and simulated EELS Al-$L_{2,3}$ edge (a) and O K edge (b) spectra. The Al-$L_{2,3}$ edge EELS simulations were done using a single scattering shell showing the significant impact of nearest neighbor O atoms. The O-K edge EELS simulations were done using 4 scattering shells. Both the change in intensity of the first peak which corresponds to the peak shoulder in the experiment and the shift in energy of the second peak are correlated with the O atom coordination.

References

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